

500V Super-Junction Power MOSFET

FEATURES

- $\bullet \quad \text{Very low FOM R}_{\text{DS(on)}} \times \text{Q}_{\text{g}} \\$
- 100% avalanche tested
- RoHS compliant

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information					
Device	TPA50R5K4C	TPP50R5K4C	TPU50R5K4C	TPD50R5K4C	
Package	TO-220F	TO-220	TO-251	TO-252	
Marking	50R5K4C	50R5K4C	50R5K4C	50R5K4C	

Absolute Maximum Ratings $T_C = 25^{\circ}C$, unless otherwise noted					
Baramatar		Cumbal	Value		11!1
Parameter		Symbol	TO-220, TO-251, TO-252	TO-220F	Unit
Drain-Source Voltage (V _{GS} = 0V)		V _{DSS}	500		٧
Continuous Drain Current	Drain Current I _D 1			А	
Pulsed Drain Current	(note1)	I _{DM}	3		А
Gate-Source Voltage		V_{GSS}	±30		V
Single Pulse Avalanche Energy	(note2)	E _{AS}	s 0.45		mJ
Avalanche Current	(note1)	I _{AR}	0.3		А
Repetitive Avalanche Energy	(note1)	E _{AR}	R 0.01		mJ
Power Dissipation (T _C = 25°C)		P _D	5.4	2.7	W
Operating Junction and Storage Temperature Range		T_J , T_{stg}	-55~+150		°C

Thermal Resistance					
Parameter	Symbol	Value		l lm:4	
Parameter	Symbol	TO-220, TO-251, TO-252	TO-220F	Unit	
Thermal Resistance, Junction-to-Case	R _{thJC}	23	46	IZ AAI	
Thermal Resistance, Junction-to-Ambient	R _{thJA}	62	80	K/W	

V3.0 www.tsinghuaicwx.com



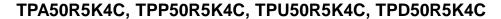
TPA50R5K4C, TPP50R5K4C, TPU50R5K4C, TPD50R5K4C

Wuxi Unigroup Microelectronics Company

		Value				
Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit
Static				!		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	500			V
Zoro Coto Voltago Proin Current		$V_{DS} = 500V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 500V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100	μA
Gate-Source Leakage	I_{GSS}	$V_{GS} = \pm 30V$			±100	nA
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4.0	V
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.3A$		4.9	5.4	Ω
Forward Transconductance (Note3)	g _{fs}	$V_{DS} = 10V, I_{D} = 0.3A$		0.5		S
Dynamic						
Input Capacitance	C _{iss}	$V_{GS} = 0V$,		53		pF
Output Capacitance	C _{oss}	$V_{DS} = 50V$,		21		
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		4		
Total Gate Charge	Q_g			1.5		nC
Gate-Source Charge	Q_{gs}	$V_{DD} = 400V, I_{D} = 1A, V_{GS} = 10V$		0.3		
Gate-Drain Charge	Q_{gd}			0.6		
Turn-on Delay Time	t _{d(on)}			16		
Turn-on Rise Time	t _r	$V_{DD} = 400V, I_{D} = 1 A,$		30		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 25\Omega$		20		
Turn-off Fall Time	t _f			35		
Drain-Source Body Diode Characteris	stics					
Continuous Body Diode Current	I _s	T 0500			1	Δ.
Pulsed Diode Forward Current	I _{SM}	$T_C = 25^{\circ}C$			3	Α
Body Diode Voltage	V _{SD}	$T_J = 25^{\circ}\text{C}, I_{SD} = 1\text{A}, V_{GS} = 0\text{V}$		0.9	1.2	V
Reverse Recovery Time	t _{rr}			35		ns
Reverse Recovery Charge	Q _{rr}	$V_R = 400V, I_F = I_S,$ $di_F/dt = 100A/\mu s$		0.1		μC
Peak Reverse Recovery Current	I _{rrm}	1,		1.4		А

Notes

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. I_{AS} = 0.3A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25 $^{\circ}$ C
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 1%

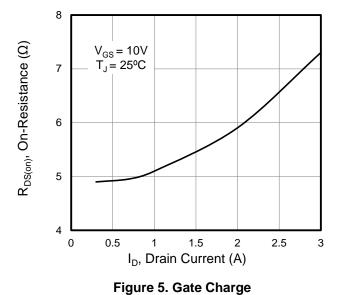




Typical Characteristics $T_J = 25^{\circ}\text{C}$, unless otherwise noted

Figure 1. Output Characteristics 2.5 20V 10V 2 6V I_D, Drain Current (A) 5.5V 5V 1.5 4.5V 1 0.5 0 5 10 15 20 V_{DS}, Drain-to-Source Voltage (V)

Figure 3. On-Resistance vs. Drain Current



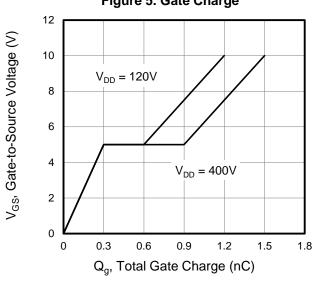


Figure 2. Transfer Characteristics

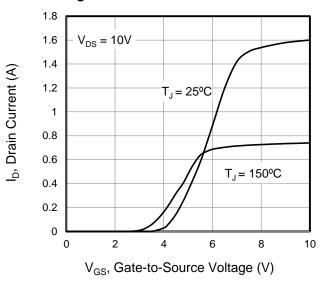


Figure 4. Capacitance

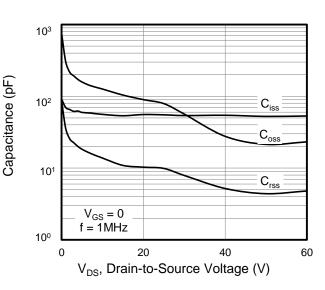
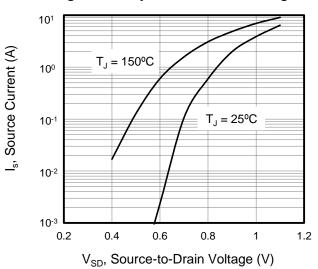


Figure 6. Body Diode Forward Voltage



Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted

Figure 7. On-Resistance vs.

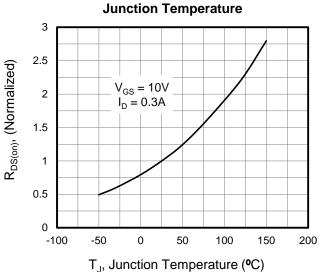


Figure 9. Transient Thermal Impedance TO-220/TO-251/TO-252

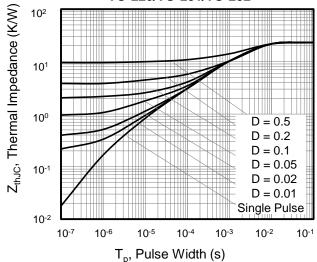


Figure 8. Threshold Voltage vs. Junction Temperature

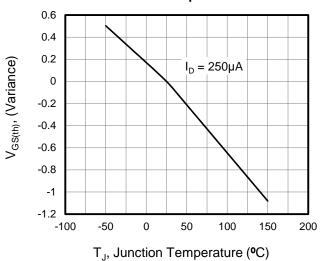


Figure 10. Transient Thermal Impedance

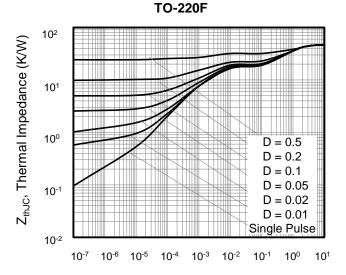




Figure A: Gate Charge Test Circuit and Waveform

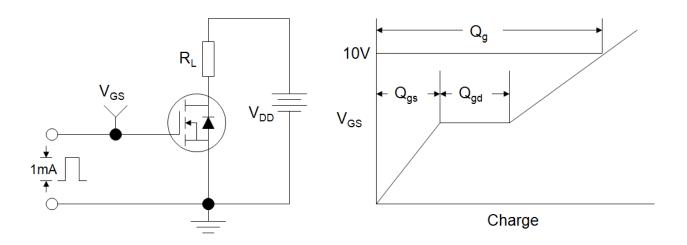


Figure B: Resistive Switching Test Circuit and Waveform

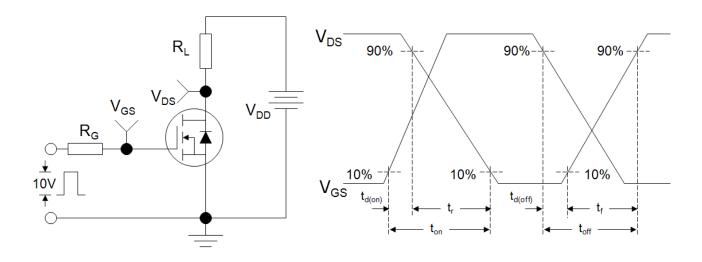
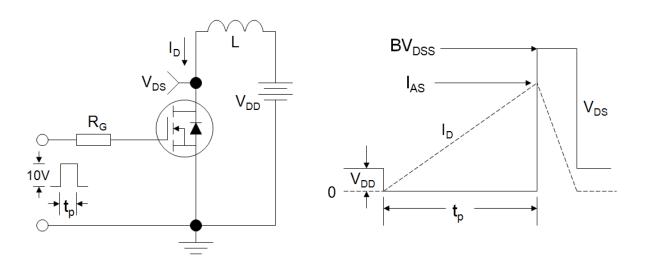


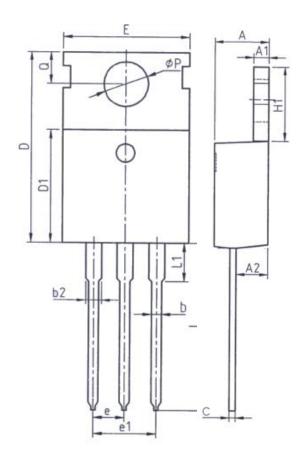
Figure C: Unclamped Inductive Switching Test Circuit and Waveform

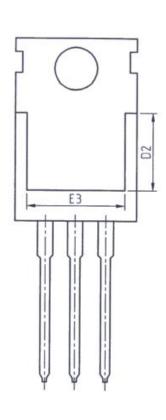


V3.0 5 www.tsinghuaicwx.com



TO-220



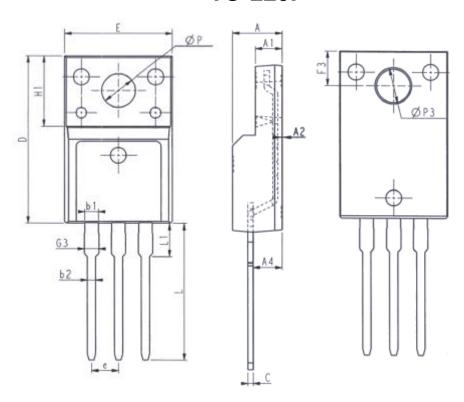


Unit: mm				
Symbol	Min.	Max.		
Α	4. 37	4. 77		
A1	1. 25	1. 45		
A2	2. 20	2. 60		
b	0. 70	0. 95		
b2	1. 17	1. 47		
С	0. 40	0. 65		
D	15. 10	16. 10		
D1	8. 80	9. 40		
D2	5. 50	_		

Unit: mm				
Symbol	Min.	Max.		
E	9. 70	10. 30		
E3	7. 00	-		
е	2. 54BSC			
e1	5. 08	BBSC		
H1	6. 25	6. 85		
L	12. 75	13.80		
L1	-	3. 40		
Р	3. 40	3. 80		
Q	2. 60	3. 00		



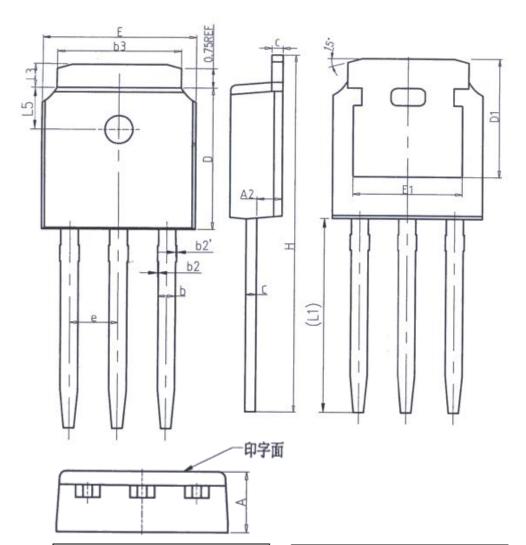




Unit: mm			l	Jnit: mn	1
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9. 96	10. 36	L	12. 68	13. 28
Α	4. 50	4. 90	L1	2. 93	3. 13
A1	2. 34	2. 74	Р	3. 03	3. 38
A2	0.30	0. 60	P3	3. 15	3. 65
A4	2. 56	2. 96	F3	3. 15	3. 45
С	0. 40	0. 65	G3	1. 25	1. 55
D	15. 57	16. 17	b1	1. 18	1. 43
H1	6. 70REF		b2	0. 70	0. 95
e	2. 54	2. 54BSC			



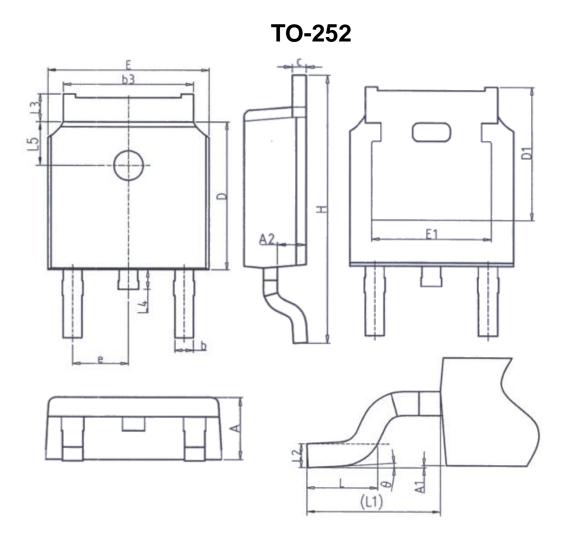
TO-251



Unit: mm				
Symbol	Min.	Max.		
Α	2. 20	2. 40		
A2	0. 97	1. 17		
b	0. 68	0.90		
b2	0.00	0.10		
b2′	0.00	0.10		
b3	5. 20	5. 50		
С	0. 43	0. 63		
D	5. 98	6. 22		

Unit: mm				
Symbol	Min.	Max.		
D1	5. 30	REF		
E	6. 40	6. 80		
E1	4. 63	-		
е	2. 286BSC			
Н	16. 22	16. 82		
L1	9. 15	9. 65		
L3	0.88	1. 28		
L5	1. 65	1. 95		





Unit: mm				
Symbol	Min.	Max.		
Α	2. 20	2. 40		
A1	0.00	0. 20		
A2	0. 97	1. 17		
b	0. 68	0. 90		
b3	5. 20	5. 50		
С	0. 43	0. 63		
D	5. 98	6. 22		
D1	5. 30REF			
E	6. 40	6. 80		
E1	4. 63	_		

Unit: mm				
Symbol	Min.	Max.		
е	2. 286BSC			
Н	9. 40	10.50		
L	1. 38	1. 75		
L1	2. 90REF			
L2	0. 51	IBSC		
L3	0.88	1. 28		
L4	- 1.00			
L5	1. 65	1. 95		
θ	θ 0°			

TPA50R5K4C, TPP50R5K4C, TPU50R5K4C, TPD50R5K4C



Wuxi Unigroup Microelectronics Company

Disclaimer

All product specifications and data are subject to change without notice.

For documents and material available from this datasheet, Wuxi Unigroup does not warrant or assume any legal liability or responsibility for the accuracy, completeness of any product or technology disclosed hereunder.

No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document or by any conduct of Wuxi Unigroup.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling Wuxi Unigroup products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Wuxi Unigroup for any damages arising or resulting from such use or sale.

Wuxi Unigroup disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Wuxi Unigroup's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

Wuxi Unigroup Microelectronics CO., LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

In the event that any or all Wuxi Unigroup products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

Information (including circuit diagrams and circuit parameters) herein is for example only. It is not guaranteed for volume production. Wuxi Unigroup believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

V3.0 www.tsinghuaicwx.com